

### Features

- Saturated Power: 32 W
- Drain Efficiency: 66%
- Small Signal Gain: 17 dB
- DFN 3 x 4 12 L Plastic Package
- RoHS\* Compliant

### Applications

- Avionics - TACAN, DME, IFF
- Military Radio
- L, S, C-band Radar
- Electronic Warfare
- ISM
- General Amplification

### Description

The MAPC-A3007-AD is a 32 W packaged, unmatched transistor utilizing a high performance, 0.15  $\mu\text{m}$  GaN on SiC production process. This transistor supports both defense and commercial related applications.

Offered in a thermally-enhanced flange package, the MAPC-A3007-AD provides superior performance under CW operation allowing customers to improve SWaP-C benchmarks in their next generation systems.

### Typical RF Performance:

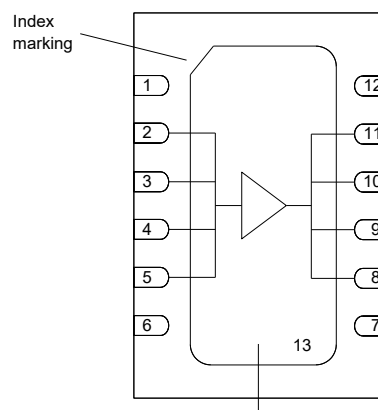
- Measured at CW =  $P_{\text{sat}}$ , defined at  $P_{\text{IN}} = 32 \text{ dBm}$ .  
 $V_{\text{DS}} = 28 \text{ V}$ ,  $I_{\text{DQ}} = 250 \text{ mA}$ ,  $T_{\text{C}} = 25^\circ\text{C}$

Frequency (GHz)	Output Power (dBm)	Gain (dB)	$\eta_{\text{D}}$ (%)
3.5	45.6	13.4	63.2
3.6	45.4	13.0	66.1
3.7	45.0	13.0	65.9



3 x 4 mm PDFN-12LD

### Functional Schematic



Source (metallized backside)

### Pin Configuration

Pin #	Pin Function	Function
2,3,4,5	$\text{RF}_{\text{IN}} / V_{\text{G}}$	RF Input / Gate
8,9,10,11	$\text{RF}_{\text{OUT}} / V_{\text{D}}$	RF Output / Drain
1,6,7,12,13	Flange <sup>1</sup>	Ground / Source

1. The flange on the package bottom must be connected to RF, DC and thermal ground.

### Ordering Information

Part Number	MOQ Increment
MAPC-A3007-AD000	Bulk
MAPC-A3007-ADTR1	Tape and Reel
MAPC-A3007-ADSB1	Sample Board

\* Restrictions on Hazardous Substances, compliant to current RoHS EU directive.

**RF Electrical Specifications: Freq. = 3.7 GHz, T<sub>A</sub> = +25°C, V<sub>DS</sub> = 28 V, I<sub>DQ</sub> = 250 mA**

Parameter	Conditions	Symbol	Min.	Typ.	Max.	Units
Saturated Power	P <sub>IN</sub> = 33 dBm, 1% 25 μs PW	P <sub>SAT</sub>	28.1	33.1	50.1	W
Drain Efficiency	P <sub>IN</sub> = 33 dBm, 1% 25 μs PW	η <sub>SAT</sub>	58	64.5	90	%
Low Power Gain	P <sub>IN</sub> = 10 dBm, 1% 25 μs PW	G <sub>SS</sub>	10	15.5	22	dB

Note: Final testing and screening for all transistor sales is performed using the MAPC-A3007-ADSB1 at 3.7 GHz.

**Absolute Maximum Ratings<sup>2,3</sup>**

Parameter	Absolute Maximum
Drain-Source Voltage	84 V
Gate Voltage	-10, +2 V
Drain Current	3.0 A
Gate Current	7.2 mA
Storage Temperature	-55°C to +150°C
Mounting Temperature	+245°C
Junction Temperature <sup>4,5</sup>	+225°C
Operating Temperature	-40°C to +85°C

2. Exceeding any one or combination of these limits may cause permanent damage to this device.
3. MACOM does not recommend sustained operation near these survivability limits.
4. Operating at nominal conditions with T<sub>J</sub> ≤ +225 °C will ensure MTTF > 1 x 10<sup>6</sup> hours.
5. Junction Temperature (T<sub>J</sub>) = T<sub>C</sub> + Θ<sub>JC</sub> \* (V \* I)  
Typical thermal resistance (Θ<sub>JC</sub>) = 3.65 °C/W for CW.
  - a) For T<sub>C</sub> = +25°C,  
T<sub>J</sub> = 93 °C @ P<sub>DISS</sub> = 18.5 W
  - b) For T<sub>C</sub> = +85°C,  
T<sub>J</sub> = 153 °C @ P<sub>DISS</sub> = 18.7 W

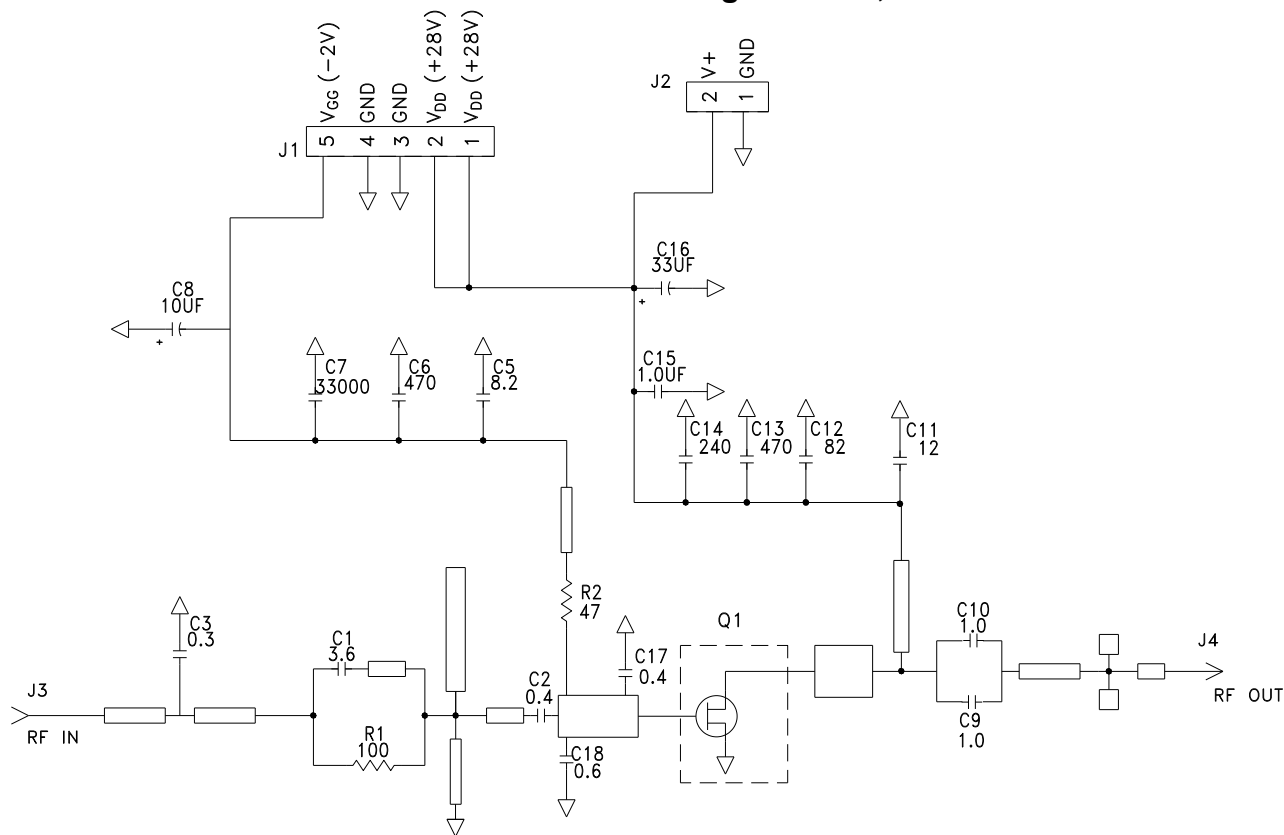
**Handling Procedures**

Please observe the following precautions to avoid damage:

**Static Sensitivity**

These electronic devices are sensitive to electrostatic discharge (ESD) and can be damaged by static electricity. Proper ESD control techniques should be used when handling these devices.

Evaluation Test Fixture and Recommended Tuning Solution, 3.5 - 3.7 GHz



**Description**

Parts measured on evaluation board (20-mil thick RO4350). Matching is provided using a combination of lumped elements and transmission lines as shown in the simplified schematic above. Recommended tuning solution component placement, transmission lines, and details are shown on the next page.

**Biasing Sequence**

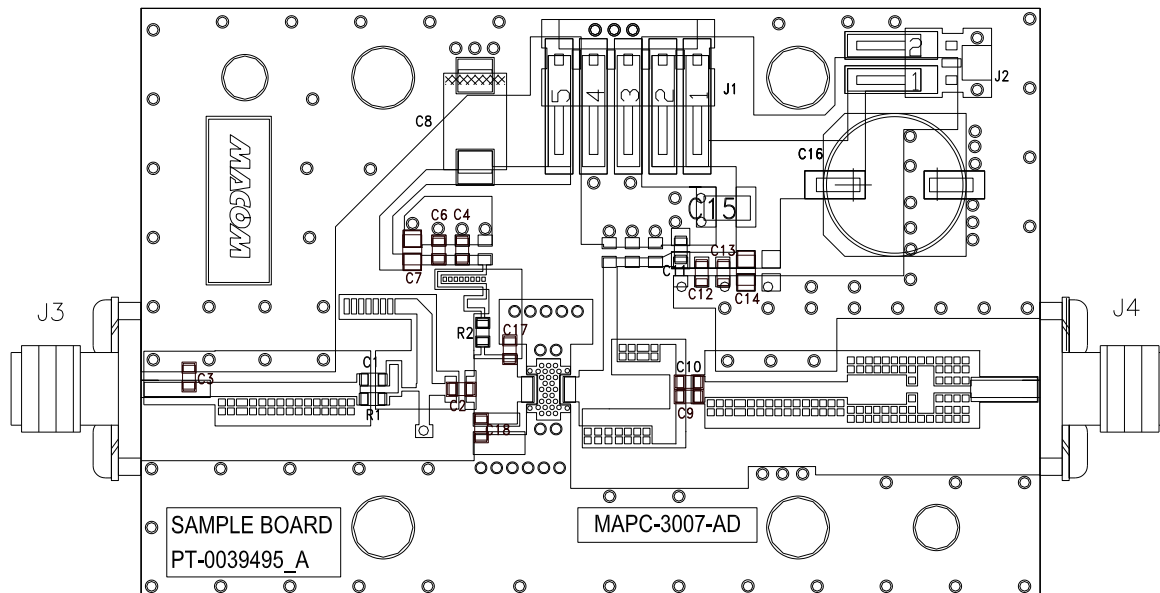
**Bias ON**

1. Ensure RF is turned off
2. Apply pinch-off voltage of -5 V to the gate
3. Apply nominal drain voltage
4. Bias gate to desired quiescent drain current
5. Apply RF

**Bias OFF**

1. Turn RF off
2. Apply pinch-off voltage of -5V to the gate
3. Turn-off drain voltage
4. Turn-off gate voltage

**Evaluation Test Fixture and Recommended Tuning Solution, 3.5 - 3.7 GHz**



**Assembly Parts List**

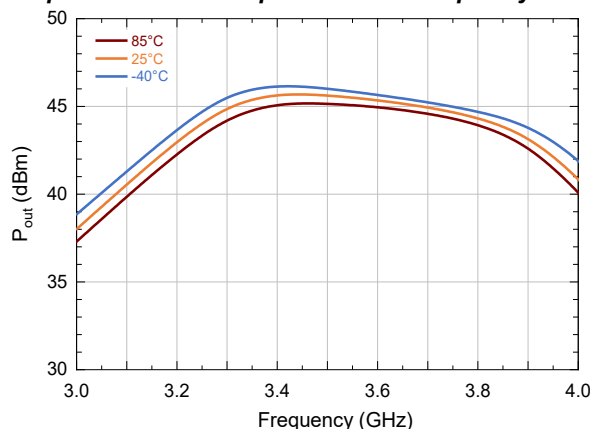
Reference Designator	Description	Qty.
C1	3.6pF 0603in T0.1p 125C 250V ATC600S	1
C2, C17	0.4pF 0603in T0.05p 125C 250V ATC600S	2
C18	0.6pF 0603in T0.1p 125C 250V ATC600S	1
C3	0.3pF 0603in T0.1p 125C 250V ATC600S	1
C5	8.2pF 0603in T0.25p 125C 250V ATC600S	2
C6, C13	470pF 0603in T5% X7R 100V ACX	2
C7	33000pF 0805 X7R 100V	1
C8	10UF 2312 16V TANTALUM	1
C9, C10	1.0pF 0603in T0.05p 125C 250V ATC600S	2
C11	12pF 0603in T5% 125C 250V ATC600S	1
C12	82pF 0603in T5% 125C 250V ATC600S	1
C14	240pF 0805in T5% 125C 250V ATC600F	1
C15	1.0UF 1210 T10% X7R 100V MUR GRM23ER	1
C16	33UF T20% G CASE PANASONIC ELECTROLYTIC	1
R1	100 OHMS 0603 T1% 1/16W	1
R2	47 OHMS 0603 T1% 1/16W	1
J1	HEADER RT>PLZ .1CEN LK 5POS	1
J2	HEADER RT>PLZ.1CEN LK 2 POS	1
J3, J4	CONN SMA PANEL MOUNT JACK FLANGE 4-HOLE BLUNT POST	2
-	PCB RO4350B 0.020" THK	1
Q1	MAPC-A3007-AD GaN Transistor	1

### Typical Performance Curves as Measured in the 3.5– 3.7 GHz Evaluation Test Fixture

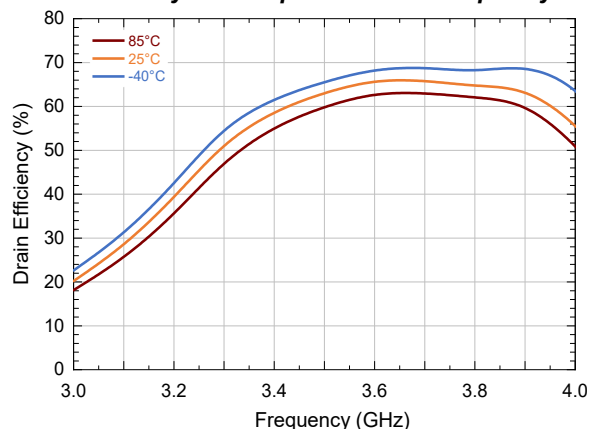
CW,  $P_{IN} = 32\text{dBm}$ ,  $V_{DS} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ , Frequency = 3.7 GHz (Unless Otherwise Noted)

For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

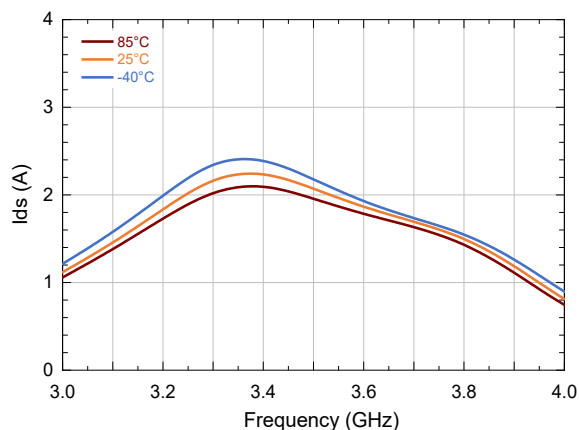
**Output Power vs. Temperature and Frequency**



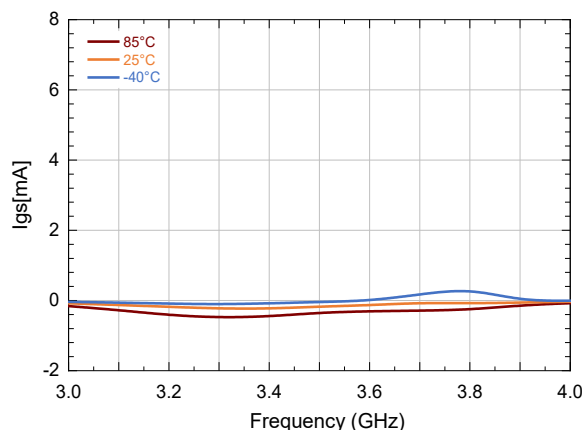
**Drain Efficiency vs. Temperature and Frequency**



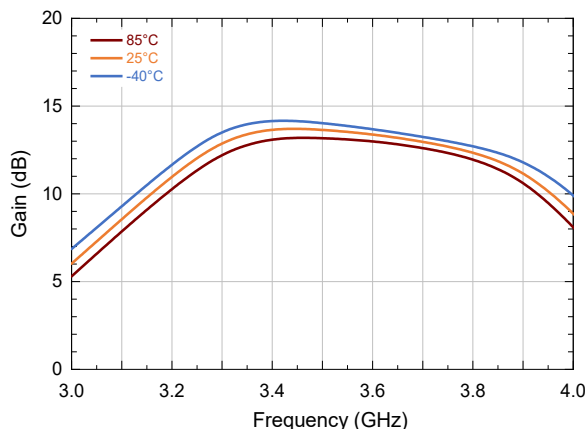
**Drain Current vs. Temperature and Frequency**



**Gate Current vs. Temperature and Frequency**



**Large Signal Gain vs. Temperature and Frequency**

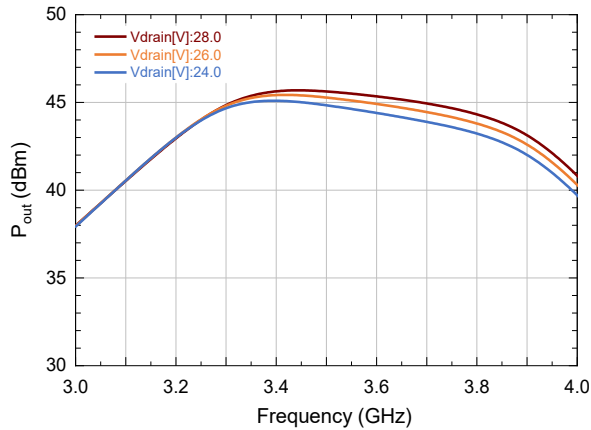


**Typical Performance Curves as Measured in the 3.5– 3.7 GHz Evaluation Test Fixture**

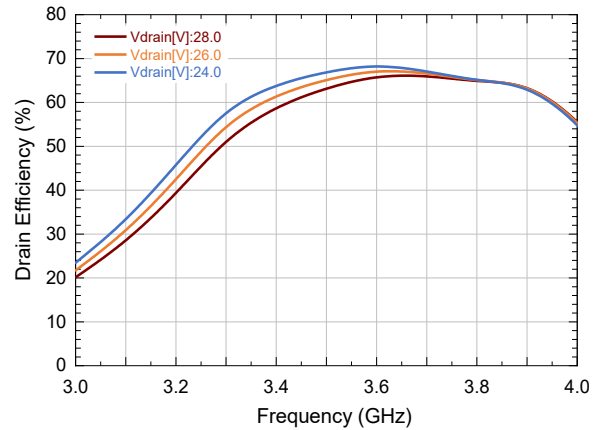
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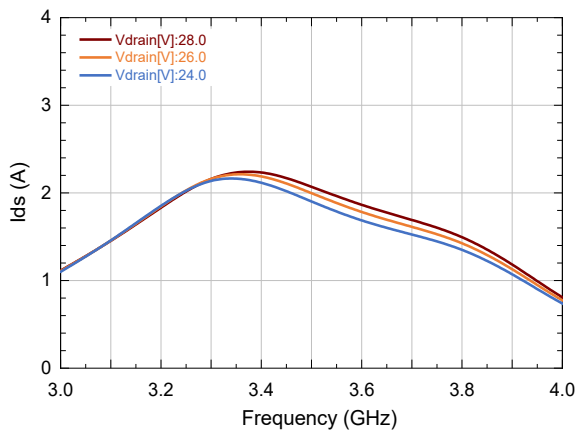
**Output Power vs.  $V_{DS}$  and Frequency**



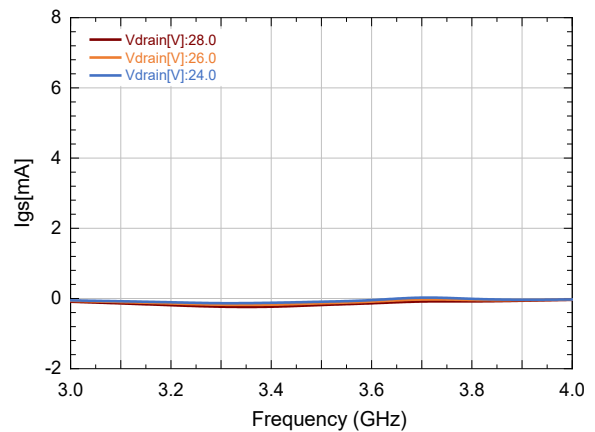
**Drain Efficiency vs.  $V_{DS}$  and Frequency**



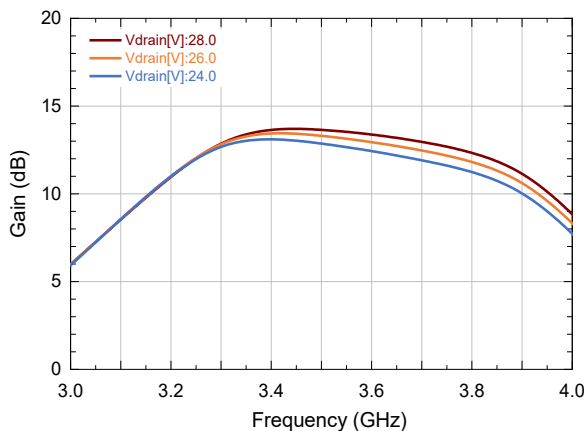
**Drain Current vs.  $V_{DS}$  and Frequency**



**Gate Current vs.  $V_{DS}$  and Frequency**



**Large Signal Gain vs.  $V_{DS}$  and Frequency**

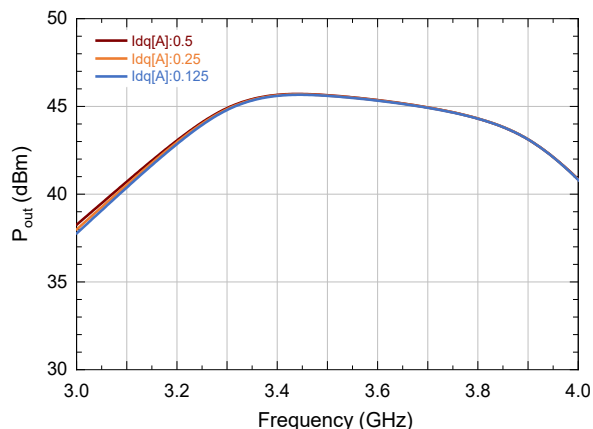


**Typical Performance Curves as Measured in the 3.5– 3.7 GHz Evaluation Test Fixture**

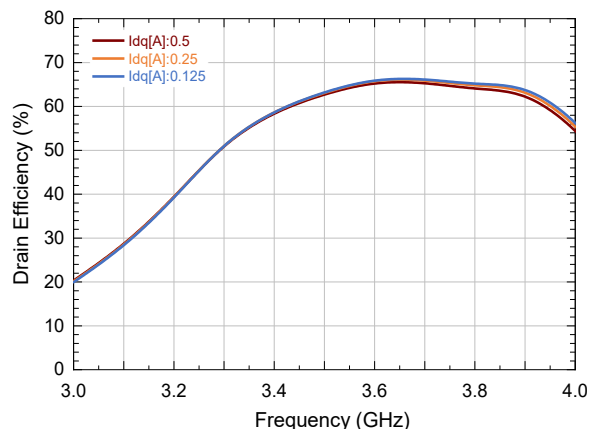
CW,  $P_{IN} = 32\text{dBm}$ ,  $V_{DS} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ , Frequency = 3.7 GHz (Unless Otherwise Noted)

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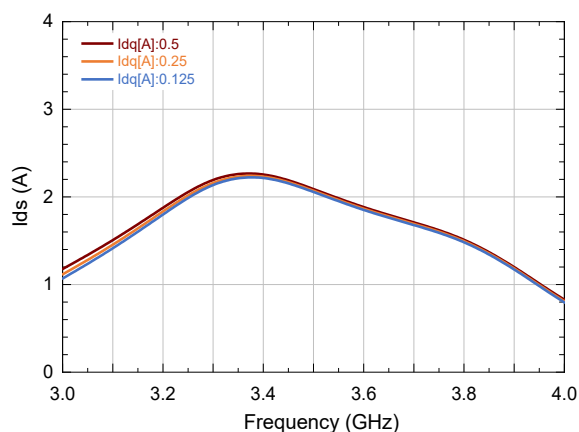
**Output Power vs.  $I_{DQ}$  and Frequency**



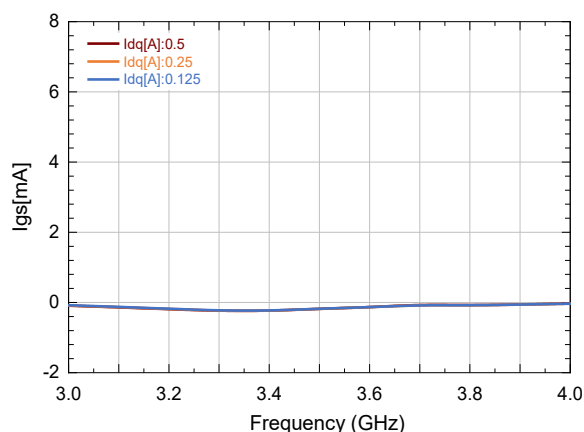
**Drain Efficiency vs.  $I_{DQ}$  and Frequency**



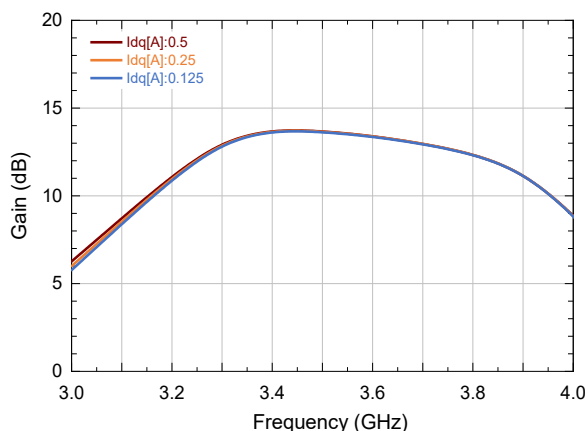
**Drain Current vs.  $I_{DQ}$  and Frequency**



**Gate Current vs.  $I_{DQ}$  and Frequency**



**Large Signal Gain vs.  $I_{DQ}$  and Frequency**

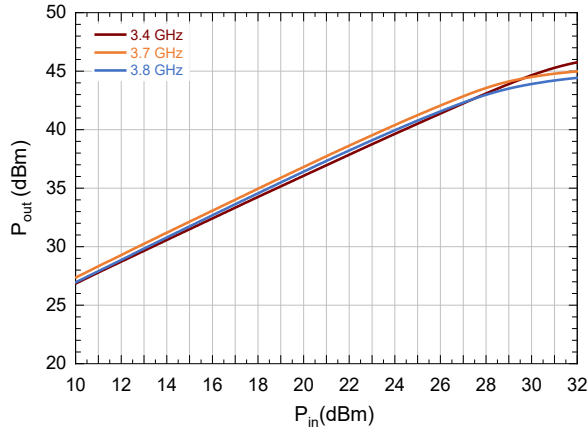


**Typical Performance Curves as Measured in the 3.5– 3.7 GHz Evaluation Test Fixture**

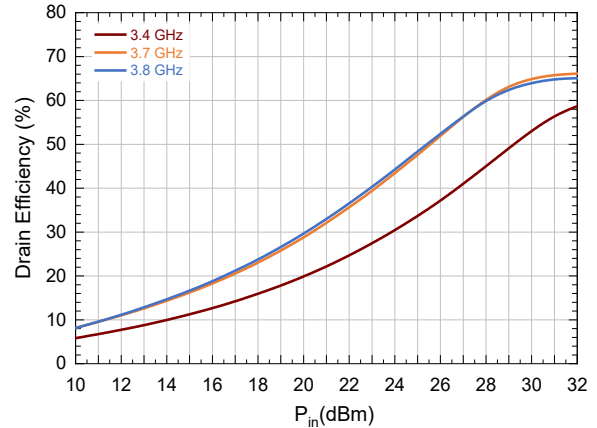
CW,  $P_{IN} = 32\text{dBm}$ ,  $V_{DS} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ , Frequency = 3.7 GHz (Unless Otherwise Noted)

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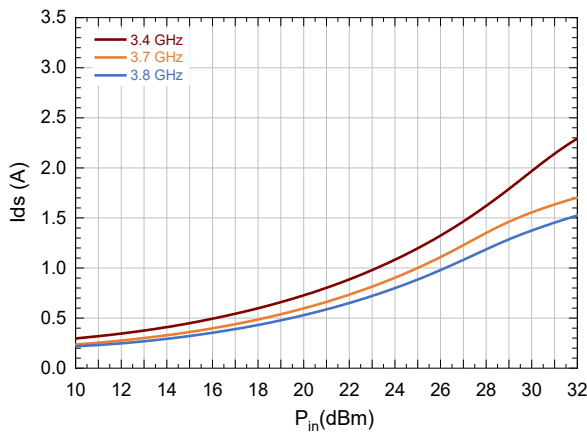
**Output Power vs. Frequency and  $P_{IN}$**



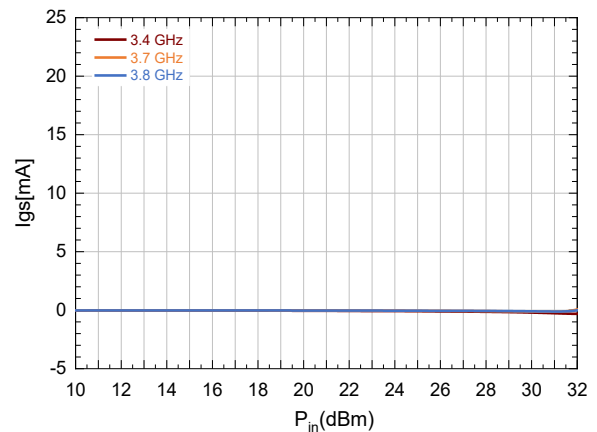
**Drain Efficiency vs. Frequency and  $P_{IN}$**



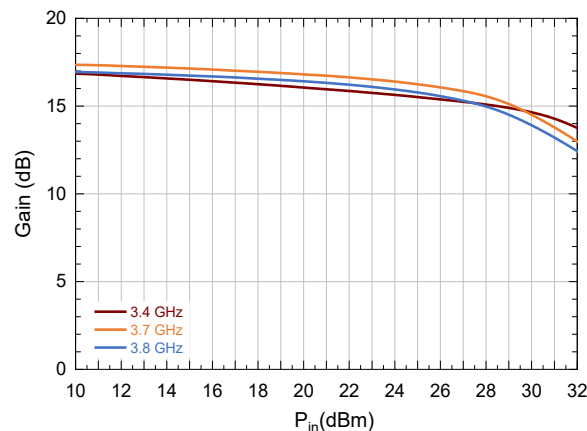
**Drain Current vs. Frequency and  $P_{IN}$**



**Gate Current vs. Frequency and  $P_{IN}$**



**Large Signal Gain vs. Frequency and  $P_{IN}$**



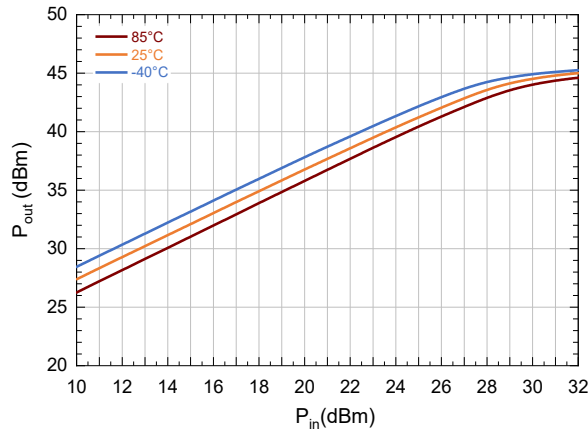


**Typical Performance Curves as Measured in the 3.5– 3.7 GHz Evaluation Test Fixture**

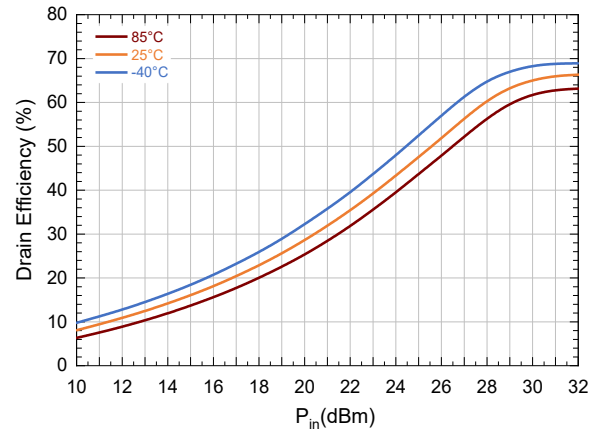
CW,  $P_{IN} = 32\text{dBm}$ ,  $V_{DS} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ , Frequency = 3.7 GHz (Unless Otherwise Noted)

For Engineering Evaluation Only – This data does not Modify MACOM’s Datasheet Limits.

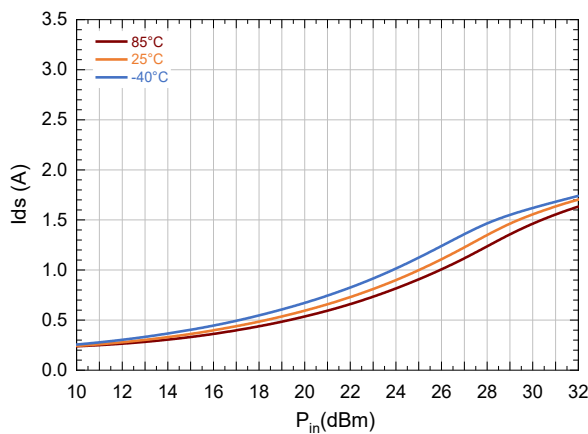
**Output Power vs. Temperature and  $P_{IN}$**



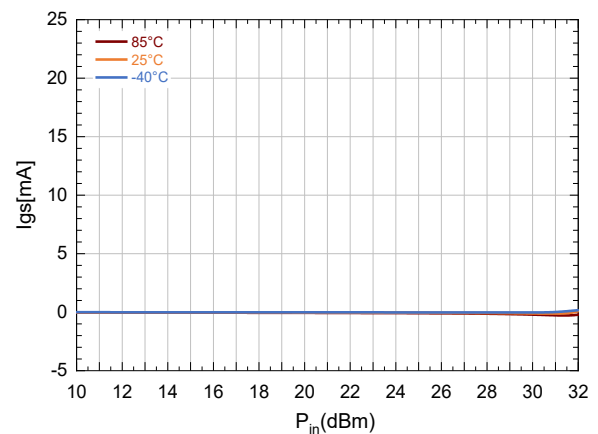
**Drain Efficiency vs. Temperature and  $P_{IN}$**



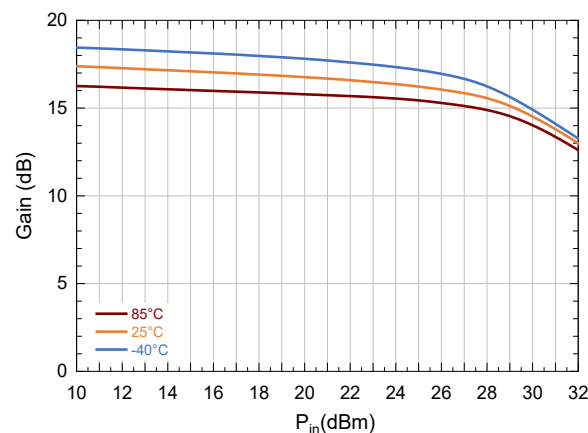
**Drain Current vs. Temperature and  $P_{IN}$**



**Gate Current vs. Temperature and  $P_{IN}$**



**Large Signal Gain vs. Temperature and  $P_{IN}$**

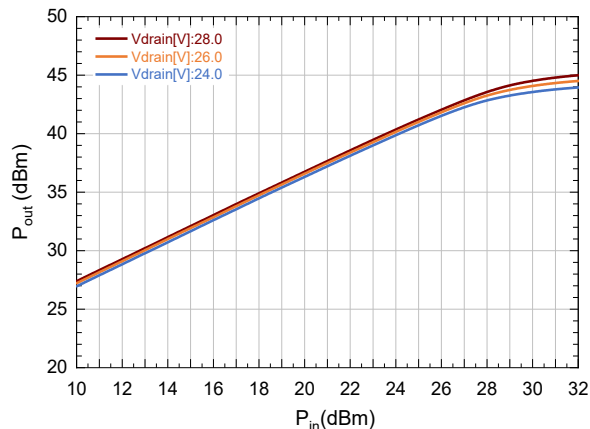


## Typical Performance Curves as Measured in the 3.5– 3.7 GHz Evaluation Test Fixture

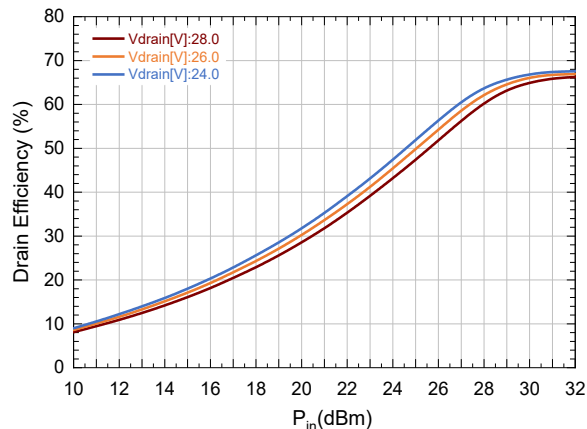
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For Engineering Evaluation Only – This data does not Modify MACOM's Datasheet Limits.

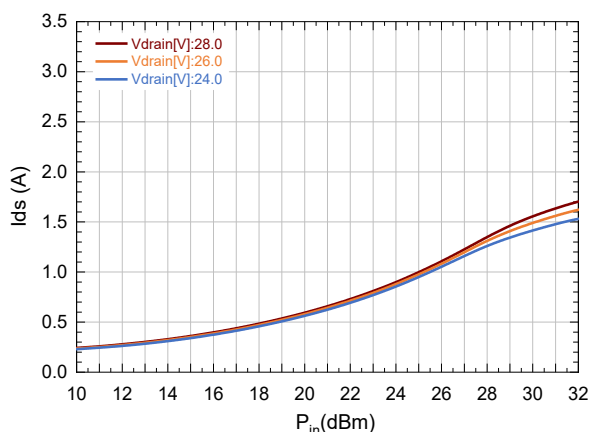
**Output Power vs.  $V_{DS}$  and  $P_{IN}$**



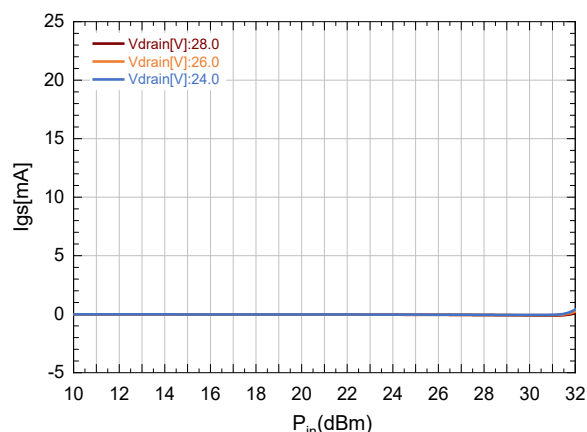
**Drain Efficiency vs.  $V_{DS}$  and  $P_{IN}$**



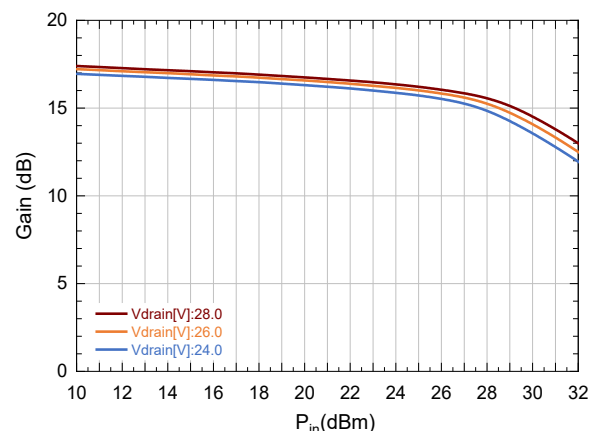
**Drain Current vs.  $V_{DS}$  and  $P_{IN}$**



**Gate Current vs.  $V_{DS}$  and  $P_{IN}$**



**Large Signal Gain vs.  $V_{DS}$  and  $P_{IN}$**

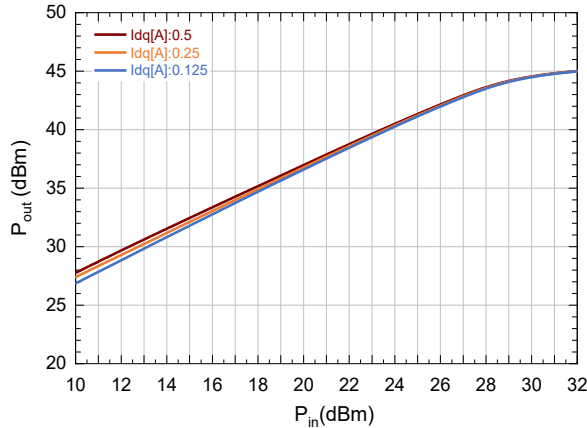


**Typical Performance Curves as Measured in the 3.5– 3.7 GHz Evaluation Test Fixture**

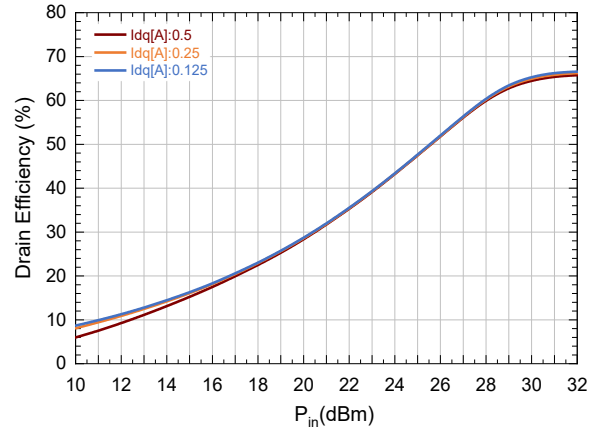
CW,  $P_{IN} = 32\text{dBm}$ ,  $V_{DS} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ , Frequency = 3.7 GHz (Unless Otherwise Noted)

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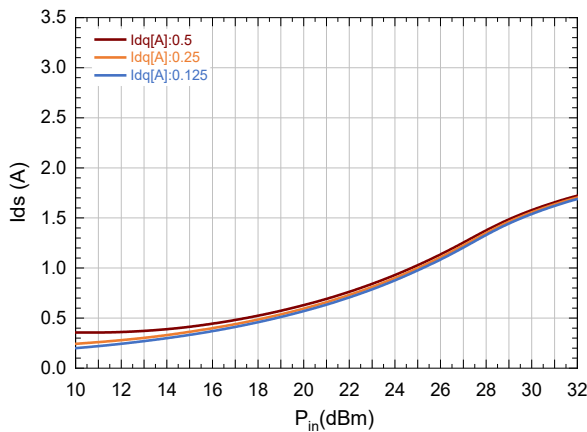
**Output Power vs.  $I_{DQ}$  and  $P_{IN}$**



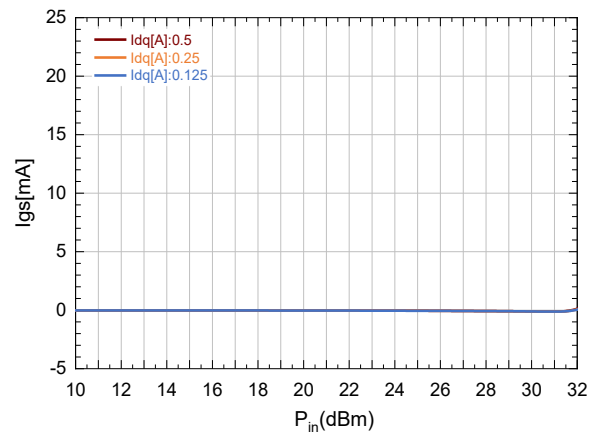
**Drain Efficiency vs.  $I_{DQ}$  and  $P_{IN}$**



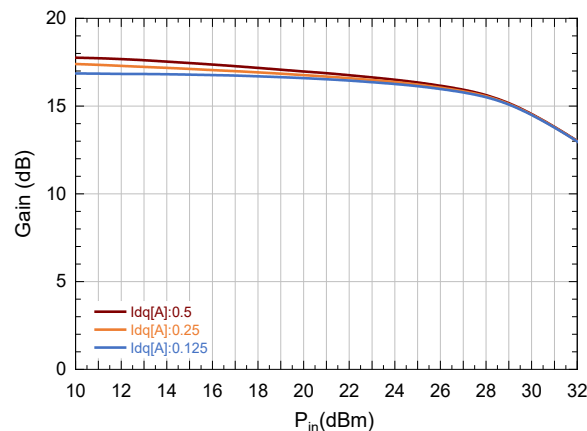
**Drain Current vs.  $I_{DQ}$  and  $P_{IN}$**



**Gate Current vs.  $I_{DQ}$  and  $P_{IN}$**

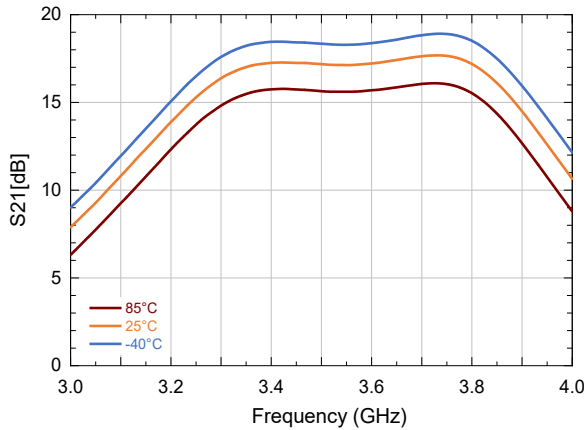


**Large Signal Gain vs.  $I_{DQ}$  and  $P_{IN}$**

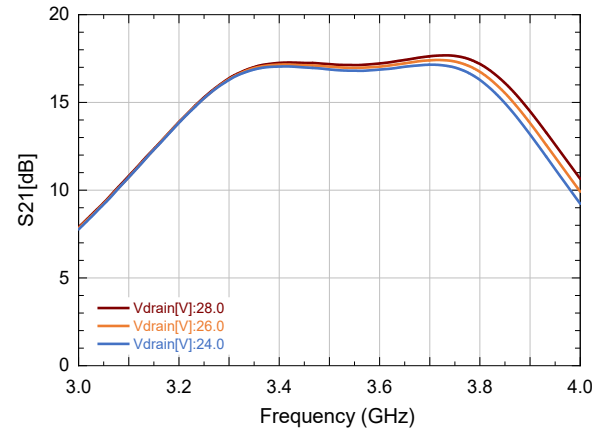


**Typical Performance Curves as Measured in the 3.5– 3.7 GHz Evaluation Test Fixture:**  
CW,  $V_{DS} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ ,  $P_{in} = -20\text{ dBm}$  (Unless Otherwise Noted)  
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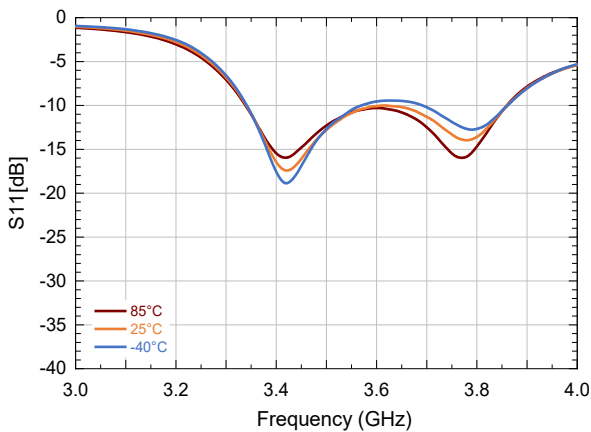
**S21 vs Frequency and Temperature**



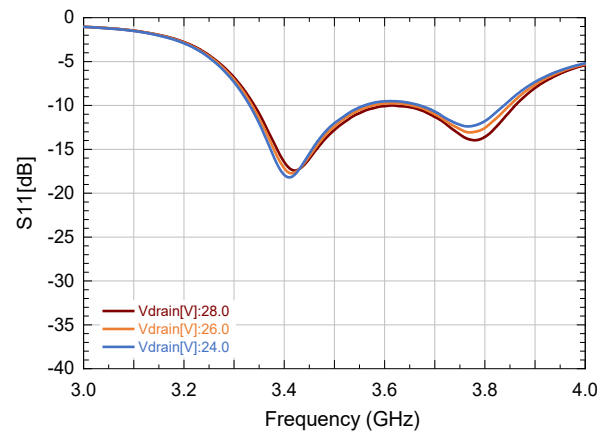
**S21 vs Frequency and  $V_{DS}$**



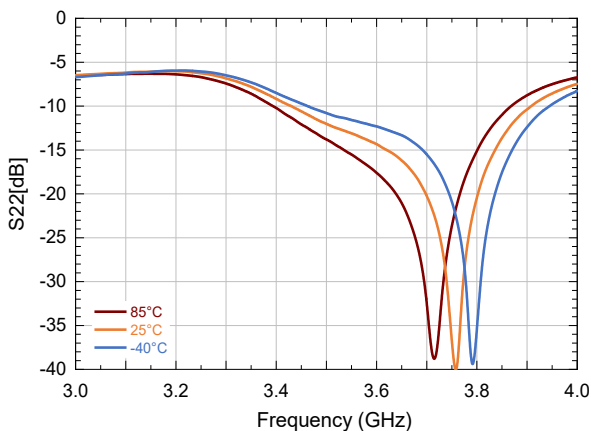
**S11 vs Frequency and Temperature**



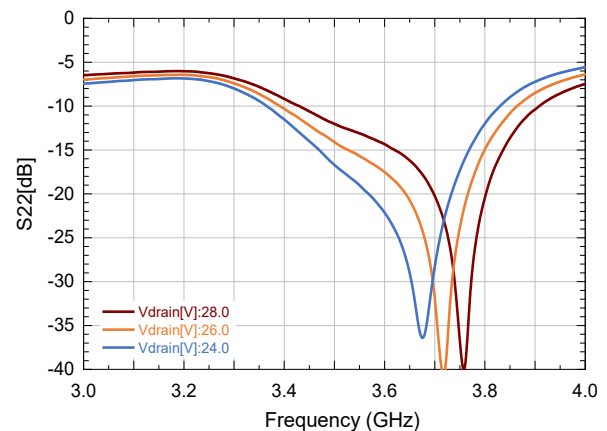
**S11 vs Frequency and  $V_{DS}$**



**S22 vs Frequency and Temperature**

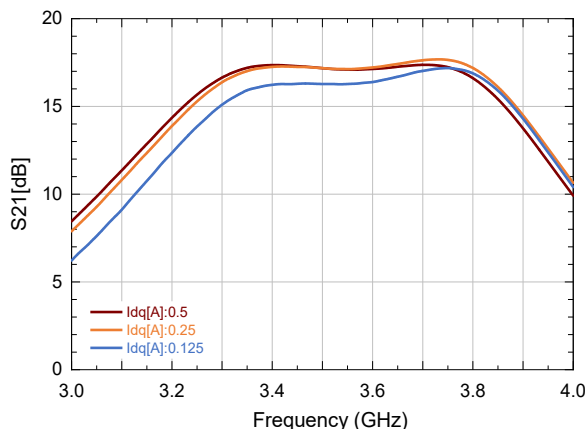


**S22 vs Frequency and  $V_{DS}$**

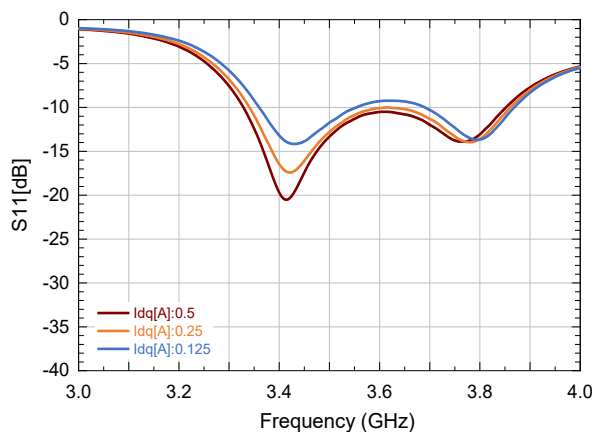


**Typical Performance Curves as Measured in the 3.5– 3.7 GHz Evaluation Test Fixture:**  
 CW,  $V_{DS} = 28\text{ V}$ ,  $I_{DQ} = 250\text{ mA}$ ,  $P_{in} = -20\text{ dBm}$  (Unless Otherwise Noted)  
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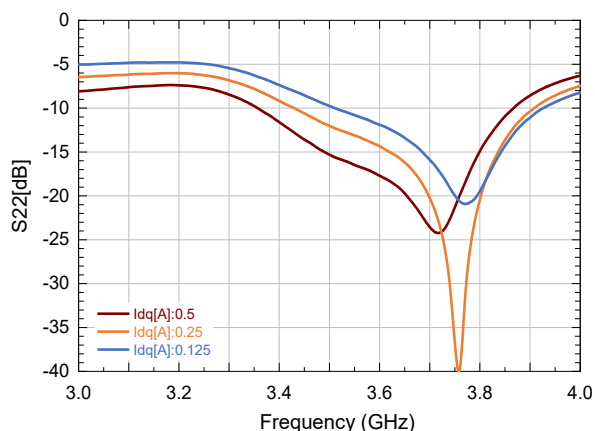
**S21 vs Frequency and  $I_{DQ}$**



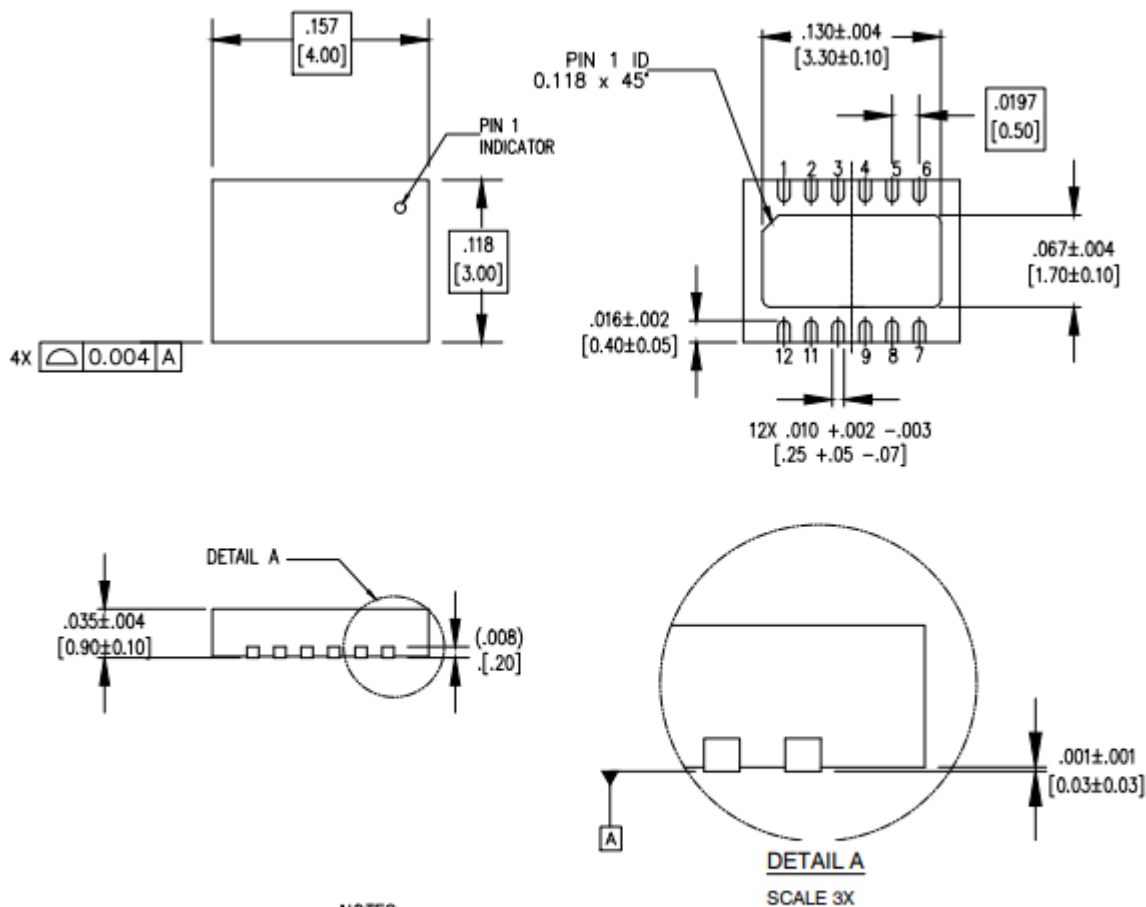
**S11 vs Frequency and  $I_{DQ}$**



**S22 vs Frequency and  $I_{DQ}$**



Lead-free 3 x 4 mm 12-Lead Package Dimensions



NOTES:

1. ALL DIMENSIONS SHOWN AS in[mm]. CONTROLLING DIMENSIONS ARE IN in. CONVERTED mm DIMENSIONS ARE NOT NECESSARILY EXACT.
2. EXPOSED LEADS 100% Sn MATTE.

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